DEMONSTRATION ON STRIP SILICON DETECTOR

USING EASY: A COMPACT READOUT SYSTEM FOR PARTICLE PHYSICS LABORATORIES



Very short introduction to strip silicon sensors

SILICON SENSORS ARE USED IN A WIDE VARIETY OF APPLICATIONS

- Nuclear physics
 - Energy measurement of charged particles & Gamma spectroscopy
 - Range of MeV
- Particle physics
 - As tracking devices: reconstruct trajectory of charged particles
 - Precise determination of particle properties
 - Vertex reconstruction
 - Momentum range of GeV
 - Impact parameters resolution: order of microns
- Satellite Experiments & Dark Matter
 - Tracking sensors
- Industrial applications
 - Security, medicine, biology

SEMICONDUCTOR

- Group IV: C, Si & Ge
- 4 covalent bonds
- 3D structure
- Compounds: e.g. GaAs





At T=0K all electrons are bound

- No conductivity At T>0K thermal excitations break some bounds
- Electrons free to move → electrical conductivity
- Vacancies can be occupied by other electrons → hole conduction as a + charged particle

SEMICONDUCTOR

- At T>0K (e.g. room temperature) electrons in conduction band recombine with holes
- Doping of silicon with group V elements (donor; P, As, Sb) adds a 5th electron weakly bound \rightarrow electron ready for conduction \rightarrow **n-type**
- Doping of silicon with group III elements (acceptor; B, Al, Ga, In) →a covalent bond is open → hole formed → p-type



THE p-n JUNCTION



A p-n junction is formed when two opposite doping type semiconductors are in contact

- The excess of electrons in the n-type diffuses to the p-type and combine with the holes (majority) and viceversa
- A region free of charge carriers appears → depletion zone

REVERSE BIASED p-n JUNCTION

Apply an external (reverse bias) voltage

- Electrons and holes may get enough energy to cross the barrier
- The depletion zone grows (size depends on dopant concentrations)
- The potential barrier becomes larger
- Diffusion across the barrier becomes more difficult (higher barrier)
- Still there is a leakage current across the junction (low current)



BASIC SILICON SENSOR SCHEME

- Usually, silicon detector are operated via a reverse biased p-n junction
- Depleted zone free of charge carriers (Except thermally generated e-h pairs → leakage current).
- Ionizing energy loss from incident particles releases e-h pairs (3,6 eV per e-h).
- Minimum ionizing particles average energy loss in silicon
 - Average ~100 e-h pairs per micro-meter
 - Average ~30.000 e-h pairs in 300 μm thick silicon sensors
 - Average deposited charge ~5 fC
- The electric field in depleted zone drifts away e-h pairs



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STRIP SILICON DETECTOR



SILICON DETECTOR CHARACTERISTICS

Curva C-V

Curva I-V



SIGNAL PROCESSING

- The sensors are operated continuously although data is read out only when acquisition is triggered
- Output depends on readout mode



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The mean value of the total energy loss is given from the Bethe-Bloch formula but the fluctuations are large due to a low number of high energy ionisations. The energy loss distribution is given by the Landau distribution







EASY - Educational Alibava System









EASY board

- Controls the detector board and communicates with the PC software.
- Xilinx device retained with support chipset
- Plug and play.
- Interface with Detector board via 34 IDC connector.
- Incorporates all control, powering for Detector Board.
- USB 2.0 interface.
- HV module to supply the detector bias.



EASY board



Detector board





Detector board

The Detector Board accommodates one "BEETLE" readout ASICs, providing 128 analogue input channels with 40MHz clocked analogue pipeline
The trigger signal is generated on the same board..

Microstrip Silicon Detector

- P-on-N silicon microstrip, polysilicon biasing resistors, AC coupled.
- 128 channels with pitch 160 µm.
- Thickness: 300 µm.
- V_{FD} < 60 V.
- I_{Leak} (@V_{FD}) < 10 nA/strip.

Laser source

Wavelength: 980nm., 5ns Pulses width











REAL DATA













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## DATA ANALYSYS





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# Charge deposition and pulse reconstruction of a **mip** particle (Sr90)







Increasing of charge collection with the depletion voltage for a mip particle (Sr90) in a 300µm strip detector.



# Cosmic rays







## Ba-133





